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IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Priority APPLICATION SERIAL NO. 09/292132
Priority FILING DATE 08/993,663 December 18, 1997
INVENTORSHIP Salman Akram et al.
ASSIGNEE Micron Technology, Inc.
Priority GROUP ART UNIT 2812
Priority EXAMINER S. Mulpuri
ATTORNEY'S DOCKET NO. MI22-1171
TITLE: Methods of Forming a Transistor Gate (As Amended)

INFORMATION DISCLOSURE STATEMENT

PURSUANT TO 37 C.F.R. §§ 1.56, 1.97 AND 1.98

In compliance with 37 C.F.R. §§ 1.56, 1.97 and 1.98, your attention is directed to the United States patents and other references listed on the attached Form PTO-1449. No admission is made regarding whether all the submitted references are prior art.

The listed references were cited by, or submitted to, the Office in the parent, co-pending application of the above-identified application. The above-identified application is a continuation application of co-pending application Serial No. 08/993,663, filed December 18, 1997. Such prior disclosure is sufficient for the above-identified application as far as copies of the references are concerned. 37 C.F.R. § 1.98(d) and MPEP § 609(2).

Respectfully submitted,

Dated: April 14, 1999

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